

FEATURES

- Initial Voltage Accuracy: 0.05%
- Low Operating Current: 10 μ A
- Low Drift: 10ppm/ $^{\circ}$ C Max
- Less Than 1 Ω Dynamic Impedance
- Available in 1.25V, 2.5V, 4.096V and 5V in SO-8 and TO-92 Packages
- 1.25V and 2.5V Available in MSOP Package
- Both Commercial and Industrial Temperature Range Parts Are Available

APPLICATIONS

- Portable Meters
- Precision Regulators
- A/D and D/A Converters
- Calibrators

DESCRIPTION

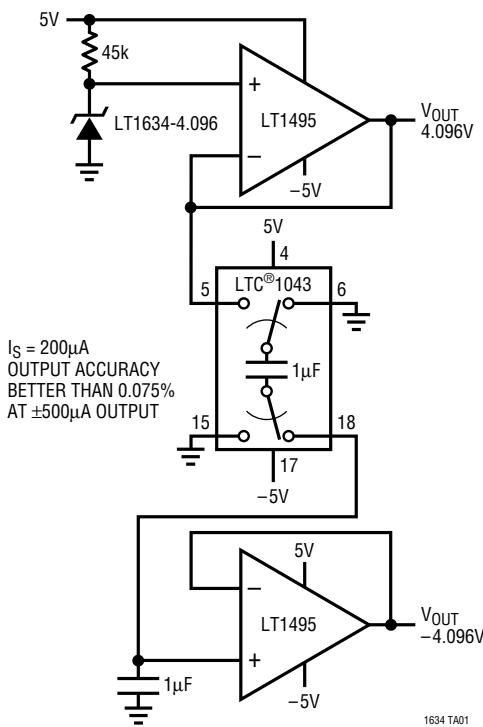
The LT[®]1634 is a micropower, precision, shunt voltage reference. The bandgap reference uses trimmed precision thin film resistors to achieve 0.05% initial voltage accuracy. Improved curvature correction technique guarantees 10ppm/ $^{\circ}$ C maximum temperature drift. Advances in design, processing and packaging techniques guarantee 10 μ A operation and low temperature cycling hysteresis. The LT1634 does not require an output compensation capacitor, but is stable with capacitive loads. Low dynamic impedance makes the LT1634 reference easy to use from unregulated supplies.

The LT1634 reference can be used as a high performance upgrade to the LM185/LM385, LT1004 and LT1034 where lower power and guaranteed temperature drift is required.

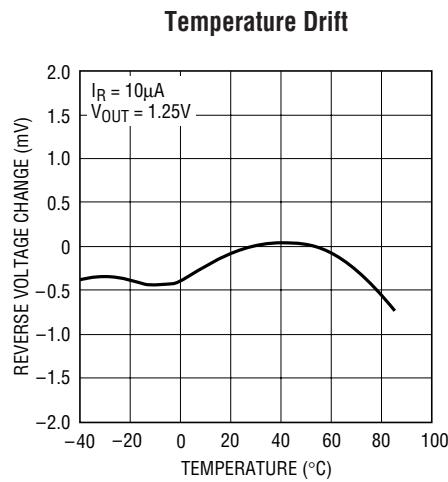
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TYPICAL APPLICATION

Super Accurate \pm 4.096V Output References



1634 TA01



1634 TA02

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Operating Current

1.25V	100mA
2.5V	50mA
4.096V, 5V	30mA
Forward Current	20mA

Operating Temperature Range

Commercial 0°C to 70°C

Industrial -40°C to 85°C

Storage Temperature Range (Note 1) ... -65°C to 150°C

Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION

TOP VIEW MS8 PACKAGE 8-LEAD PLASTIC MSOP $T_{JMAX} = 125^\circ\text{C}$, $\theta_{JA} = 250^\circ\text{C}/\text{W}$	TOP VIEW S8 PACKAGE 8-LEAD PLASTIC SO $T_{JMAX} = 125^\circ\text{C}$, $\theta_{JA} = 190^\circ\text{C}/\text{W}$		
ORDER PART NUMBER	MS8 PART MARKING	ORDER PART NUMBER	S8 PART MARKING
LT1634BCMS8-1.25 LT1634BCMS8-2.5	LTCV LTDF	LT1634ACS8-1.25 LT1634ACS8-2.5 LT1634ACS8-4.096 LT1634ACS8-5 LT1634AIS8-1.25 LT1634AIS8-2.5 LT1634AIS8-4.096 LT1634AIS8-5 LT1634BCS8-1.25 LT1634BCS8-2.5 LT1634BCS8-4.096 LT1634BCS8-5 LT1634BIS8-1.25 LT1634BIS8-2.5 LT1634BIS8-4.096 LT1634BIS8-5	1634A1 1634A2 1634A4 1634A5 634AI1 634AI2 634AI4 634AI5 1634B1 1634B2 1634B4 1634B5 634BI1 634BI2 634BI4 634BI5
BOTTOM VIEW Z PACKAGE 3-LEAD PLASTIC TO-92 $T_{JMAX} = 125^\circ\text{C}$, $\theta_{JA} = 190^\circ\text{C}/\text{W}$	ORDER PART NUMBER		
	LT1634CCZ-1.25 LT1634CCZ-2.5 LT1634CCZ-4.096 LT1634CCZ-5		

*Connected internally. Do Not Connect external circuitry to these pins.

**Connect to ground in user application.

Consult LTC Marketing for parts specified with wider operating temperature ranges.

AVAILABLE OPTIONS

TEMPERATURE	ACCURACY (%)	TEMPERATURE COEFFICIENT (ppm/°C)	PACKAGE TYPE		
			MS8	S8	Z
0°C to 70°C	0.05	10		LT1634ACS8-1.25 LT1634ACS8-2.5 LT1634ACS8-4.096 LT1634ACS8-5	
-40°C to 85°C	0.05	10		LT1634AIS8-1.25 LT1634AIS8-2.5 LT1634AIS8-4.096 LT1634AIS8-5	
0°C to 70°C	0.05	25	LT1634BCMS8-1.25 LT1634BCMS8-2.5	LT1634BCS8-1.25 LT1634BCS8-2.5 LT1634BCS8-4.096 LT1634BCS8-5	
-40°C to 85°C	0.05	25		LT1634BIS8-1.25 LT1634BIS8-2.5 LT1634BIS8-4.096 LT1634BIS8-5	
0°C to 70°C	0.20	25			LT1634CCZ-1.25 LT1634CCZ-2.5 LT1634CCZ-4.096 LT1634CCZ-5

1.25V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1634ACS8/LT1634BCMS8/LT1634BCS8/ LT1634AIS8/LT1634BIS8 ($I_R = 10\mu\text{A}$)	1.24937 -0.05	1.250	1.25062 0.05	V %
	LT1634CCZ ($I_R = 10\mu\text{A}$)	1.24750 -0.20	1.250	1.25250 0.20	V %
	LT1634ACS8 ($I_R = 10\mu\text{A}$)	● 1.24849 -0.12	1.250	1.25149 0.12	V %
	LT1634AIS8 ($I_R = 10\mu\text{A}$)	● 1.24781 -0.175	1.250	1.25218 0.175	V %
	LT1634BCS8/LT1634BCMS8 ($I_R = 10\mu\text{A}$)	● 1.24718 -0.225	1.250	1.25281 0.225	V %
	LT1634BIS8 ($I_R = 10\mu\text{A}$)	● 1.24547 -0.362	1.250	1.25453 0.362	V %
	LT1634CCZ ($I_R = 10\mu\text{A}$)	● 1.24531 -0.375	1.250	1.25469 0.375	V %
Reverse Breakdown Change with Current (Note 4)	$10\mu\text{A} \leq I_R \leq 2\text{mA}$		0.25 0.30	1 2	mV mV
	$2\text{mA} \leq I_R \leq 20\text{mA}$		2 2	8 10	mV mV
Minimum Operating Current				7	μA
Temperature Coefficient (Note 8)	LT1634A, $I_R = 10\mu\text{A}$	●	4	10	ppm/°C
	LT1634B/LT1634C, $I_R = 10\mu\text{A}$	●	10	25	ppm/°C
Reverse Dynamic Impedance (Note 5)	$10\mu\text{A} \leq I_R \leq 2\text{mA}$		0.125 0.150	0.5 1.0	Ω Ω
Low Frequency Noise (Note 6)	$I_R = 10\mu\text{A}, 0.1\text{Hz} \leq f \leq 10\text{Hz}$			10	μV _{P-P}
Hysteresis (Note 7)	$\Delta T = -40^\circ\text{C} \text{ to } 85^\circ\text{C}$ $\Delta T = 0^\circ\text{C} \text{ to } 70^\circ\text{C}$			160 40	ppm ppm

2.5V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1634ACS8/LT1634BCMS8/LT1634BCS8/ LT1634AIS8/LT1634BIS8 ($I_R = 10\mu\text{A}$)	2.49875 -0.05	2.500	2.50125 0.05	V %
	LT1634CCZ ($I_R = 10\mu\text{A}$)	2.49500 -0.20	2.500	2.50500 0.20	V %
	LT1634ACS8 ($I_R = 10\mu\text{A}$)	● 2.49700 -0.12	2.500	2.50300 0.12	V %
	LT1634AIS8 ($I_R = 10\mu\text{A}$)	● 2.49562 -0.175	2.500	2.50437 0.175	V %
	LT1634BCMS8/LT1634BCS8 ($I_R = 10\mu\text{A}$)	● 2.49437 -0.225	2.500	2.50562 0.225	V %
	LT1634BIS8 ($I_R = 10\mu\text{A}$)	● 2.49094 -0.362	2.500	2.50906 0.362	V %
	LT1634CCZ ($I_R = 10\mu\text{A}$)	● 2.49062 -0.375	2.500	2.50937 0.375	V %
Reverse Breakdown Change with Current (Note 4)	$10\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.30 0.40	1.5 3.0	mV mV
	$2\text{mA} \leq I_R \leq 20\text{mA}$	●	2 2	8 10	mV mV
Minimum Operating Current		●		8	μA
Temperature Coefficient (Note 8)	LT1634A, $I_R = 10\mu\text{A}$	●	4	10	$\text{ppm}/^\circ\text{C}$
	LT1634B/LT1634C, $I_R = 10\mu\text{A}$	●	10	25	$\text{ppm}/^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$10\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.15 0.20	0.75 1.50	Ω Ω
	$I_R = 10\mu\text{A}, 0.1\text{Hz} \leq f \leq 10\text{Hz}$			15	$\mu\text{V}_{\text{P-P}}$
Hysteresis (Note 7)	$\Delta T = -40^\circ\text{C}$ to 85°C			160	ppm
	$\Delta T = 0^\circ\text{C}$ to 70°C			40	ppm

4.096V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1634ACS8/LT1634BCS8/ LT1634AIS8/LT1634BIS8 ($I_R = 20\mu\text{A}$)	4.09395 -0.05	4.096	4.09805 0.05	V %
	LT1634CCZ ($I_R = 20\mu\text{A}$)	4.08780 -0.20	4.096	4.10419 0.20	V %
	LT1634ACS8 ($I_R = 20\mu\text{A}$)	● 4.09108 -0.12	4.096	4.10091 0.12	V %
	LT1634AIS8 ($I_R = 20\mu\text{A}$)	● 4.08883 -0.175	4.096	4.10317 0.175	V %
	LT1634BCS8 ($I_R = 20\mu\text{A}$)	● 4.08678 -0.225	4.096	4.10522 0.225	V %
	LT1634BIS8 ($I_R = 20\mu\text{A}$)	● 4.08115 -0.362	4.096	4.11085 0.362	V %
	LT1634CCZ ($I_R = 20\mu\text{A}$)	● 4.08064 -0.375	4.096	4.11137 0.375	V %
Reverse Breakdown Change with Current (Note 4)	$20\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.3 0.4	1.5 3.0	mV mV
	$2\text{mA} \leq I_R \leq 20\text{mA}$	●	6 6	15 20	mV mV
Minimum Operating Current		●		15	μA

4.096V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Temperature Coefficient (Note 8)	LT1634A, $I_R = 20\mu\text{A}$ LT1634B/LT1634C, $I_R = 20\mu\text{A}$	● ●	4 10	10 25	ppm/ $^\circ\text{C}$ ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$20\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.15 0.20	0.75 1.50	Ω Ω
Low Frequency Noise (Note 6)	$I_R = 20\mu\text{A}, 0.1\text{Hz} \leq f \leq 10\text{Hz}$		30		$\mu\text{V}_{\text{P-P}}$
Hysteresis (Note 7)	$\Delta T = -40^\circ\text{C}$ to 85°C $\Delta T = 0^\circ\text{C}$ to 70°C		160 40		ppm ppm

5V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1634ACS8/LT1634BCS8/ LT1634AIS8/LT1634BIS8 ($I_R = 20\mu\text{A}$)	4.99750 −0.05	5.000 0.05	5.00250 0.05	V %
	LT1634CCZ ($I_R = 20\mu\text{A}$)	4.99000 −0.20	5.000 0.20	5.01000 0.20	V %
	LT1634ACS8 ($I_R = 20\mu\text{A}$)	● 4.99400 −0.12	5.000 0.12	5.00600 0.12	V %
	LT1634AIS8 ($I_R = 20\mu\text{A}$)	● 4.99125 −0.175	5.000 0.175	5.00875 0.175	V %
	LT1634BCS8 ($I_R = 20\mu\text{A}$)	● 4.98875 −0.225	5.000 0.225	5.01125 0.225	V %
	LT1634BIS8 ($I_R = 20\mu\text{A}$)	● 498188 −0.362	5.000 0.362	5.01813 0.362	V %
	LT1634CCZ ($I_R = 20\mu\text{A}$)	● 4.98126 −0.375	5.000 0.375	5.01876 0.375	V %
Reverse Breakdown Change with Current (Note 4)	$20\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.3 0.4	1.5 3.0	mV mV
	$2\text{mA} \leq I_R \leq 20\text{mA}$	●	6 6	15 20	mV mV
Minimum Operating Current		●		15	μA
Temperature Coefficient (Note 8)	LT1634A, $I_R = 20\mu\text{A}$ LT1634B/LT1634C, $I_R = 20\mu\text{A}$	● ●	4 10	10 25	ppm/ $^\circ\text{C}$ ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$20\mu\text{A} \leq I_R \leq 2\text{mA}$	●	0.15 0.20	0.75 1.50	Ω Ω
Low Frequency Noise (Note 6)	$I_R = 20\mu\text{A}, 0.1\text{Hz} \leq f \leq 10\text{Hz}$		35		$\mu\text{V}_{\text{P-P}}$
Hysteresis (Note 7)	$\Delta T = -40^\circ\text{C}$ to 85°C $\Delta T = 0^\circ\text{C}$ to 70°C		160 40		ppm ppm

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: If the part is stored outside of the specific operating temperature range, the output may shift due to hysteresis.

Note 3: ESD (Electrostatic Discharge) sensitive device. Use proper ESD handling precautions.

Note 4: Output requires $0.1\mu\text{F}$ for operating current greater than 1mA .

Note 5: This parameter is guaranteed by "reverse breakdown change with current" test.

Note 6: Peak-to-peak noise is measured with a single highpass filter at 0.1Hz and 2-pole lowpass filter at 10Hz .

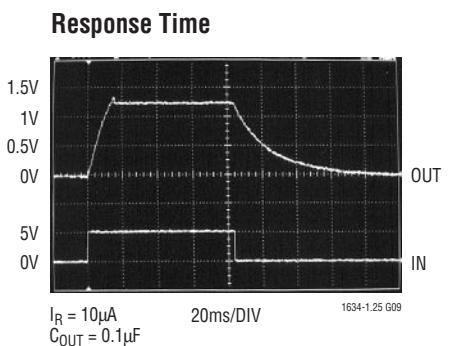
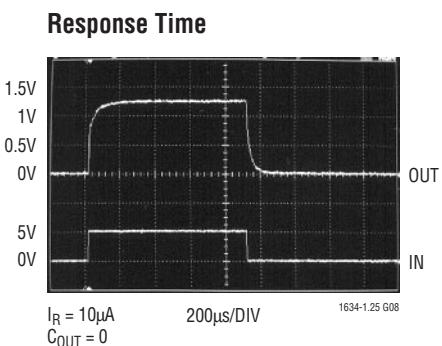
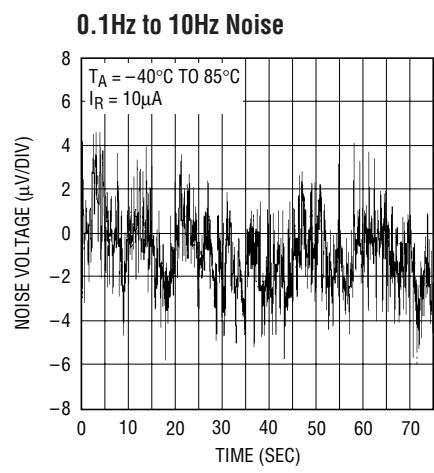
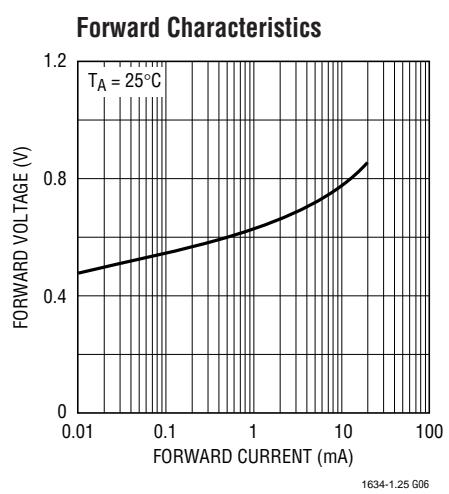
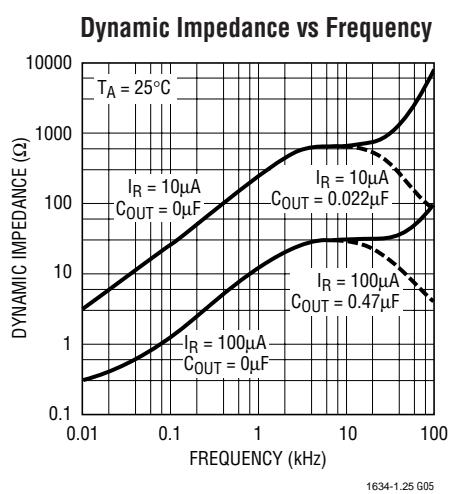
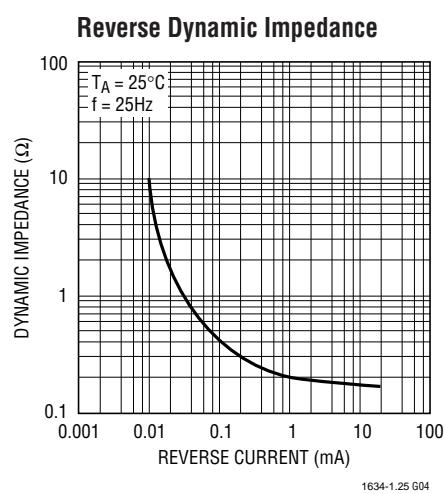
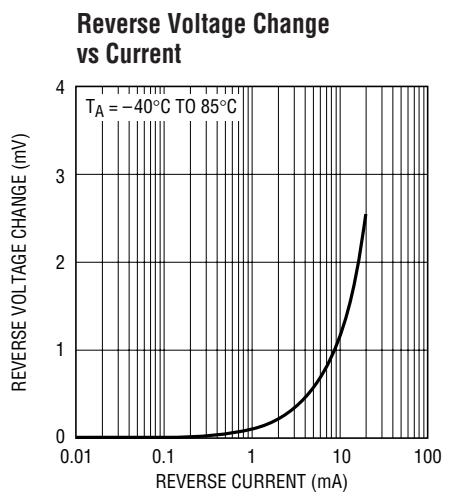
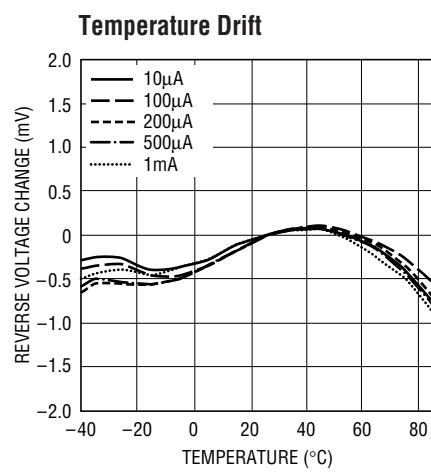
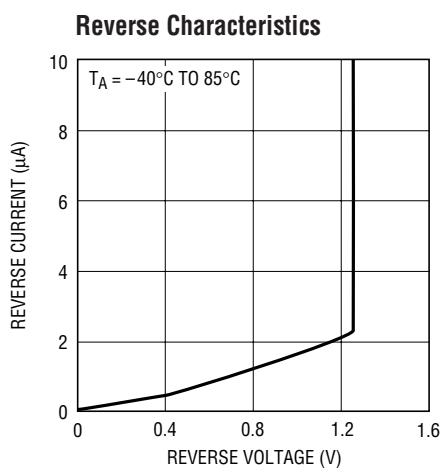
Note 7: Hysteresis in output voltage is created by package stress that differs depending on whether the IC was previously at a higher or lower temperature. Output voltage is always measured at 25°C but the IC is cycled to 85°C or -40°C before successive measurements. Hysteresis is roughly proportional to the square of the temperature change. Hysteresis is not normally a problem for operational temperature excursions where the instrument might be stored at high or low temperature.

Note 8: Temperature coefficient is calculated from the minimum and maximum output voltage measured at T_{MIN} , Room and T_{MAX} as follows:

$$TC = (V_{\text{OMAX}} - V_{\text{OMIN}})/(T_{\text{MAX}} - T_{\text{MIN}})$$

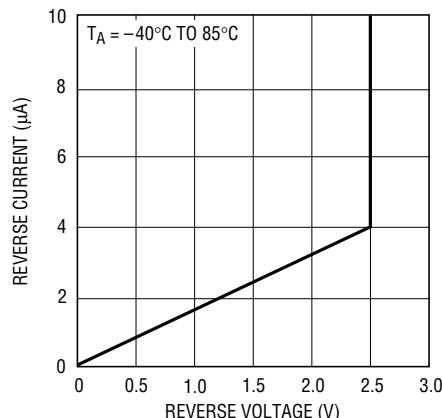
Incremental slope is also measured at 25°C .

1.25V TYPICAL PERFORMANCE CHARACTERISTICS

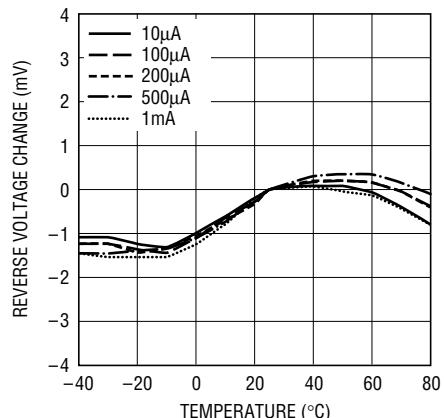


2.5V TYPICAL PERFORMANCE CHARACTERISTICS

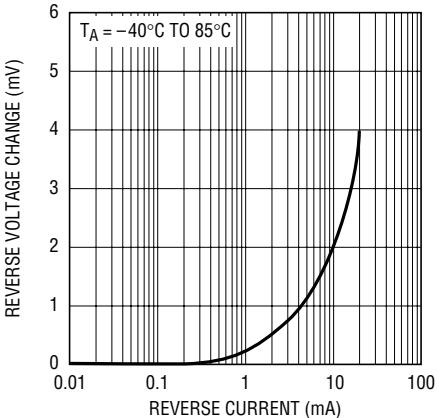
Reverse Characteristics



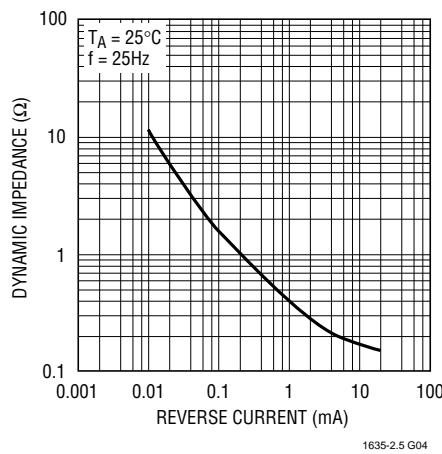
Temperature Drift



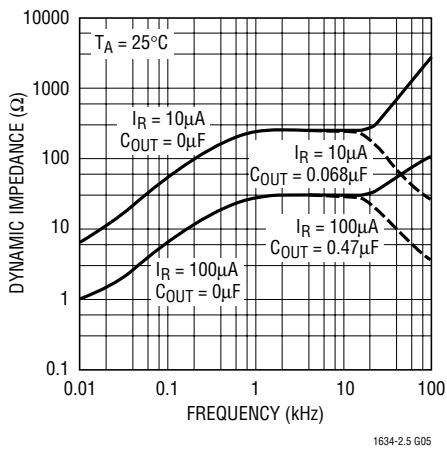
Reverse Voltage Change vs Current



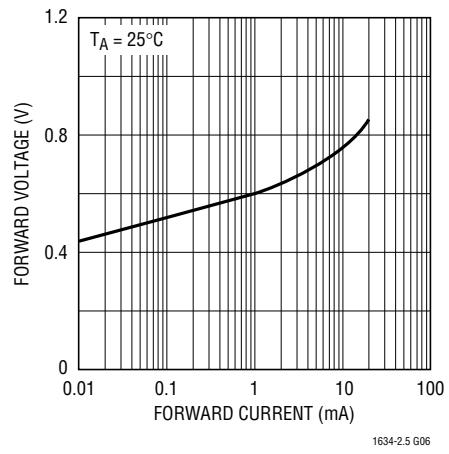
Reverse Dynamic Impedance



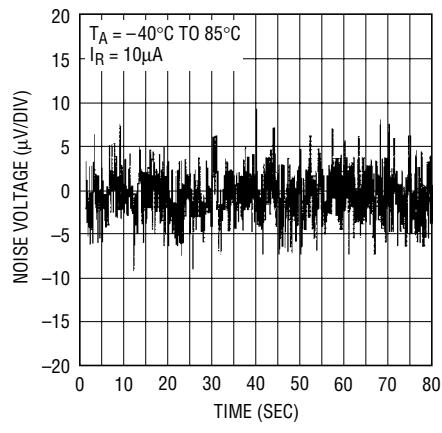
Dynamic Impedance vs Frequency



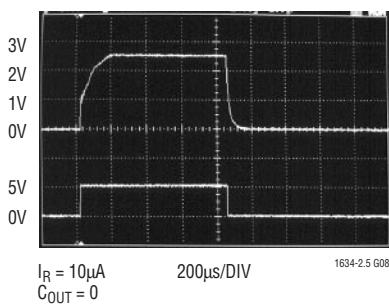
Forward Characteristics



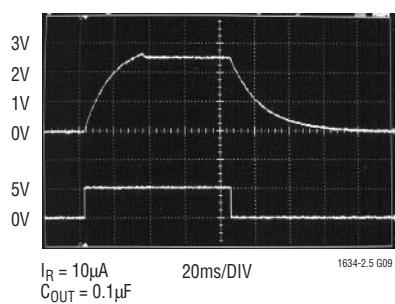
0.1Hz to 10Hz Noise



Response Time

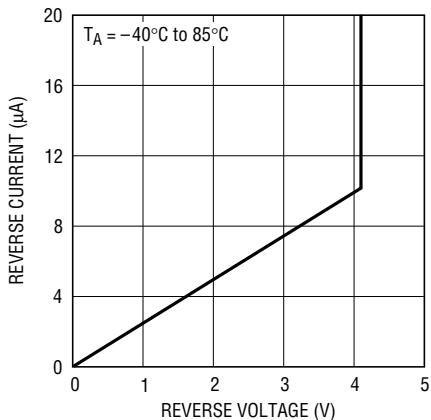


Response Time



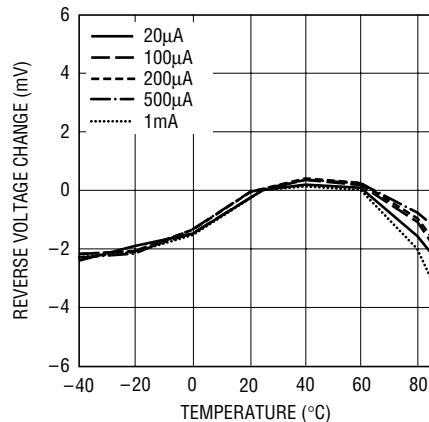
4.096V TYPICAL PERFORMANCE CHARACTERISTICS

Reverse Characteristics



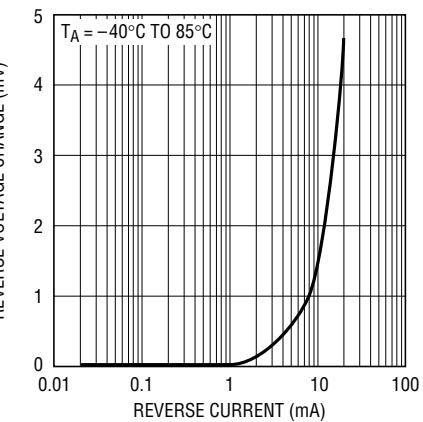
1634-4 G01

Temperature Drift



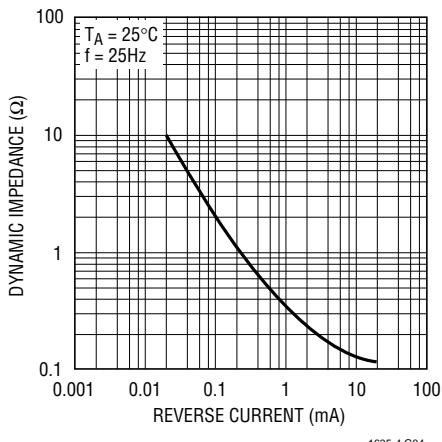
1634-4 G02

Reverse Voltage Change vs Current



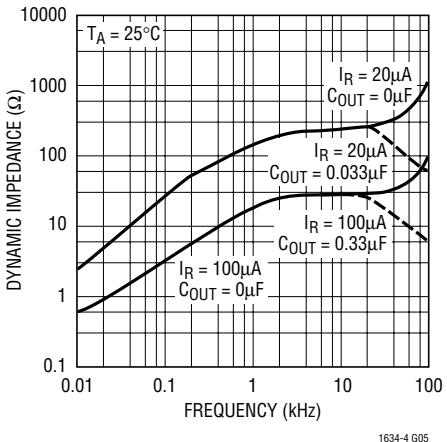
1634-4 G03

Reverse Dynamic Impedance



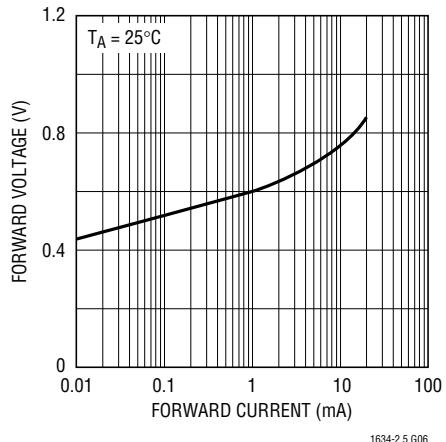
1634-4 G04

Dynamic Impedance vs Frequency



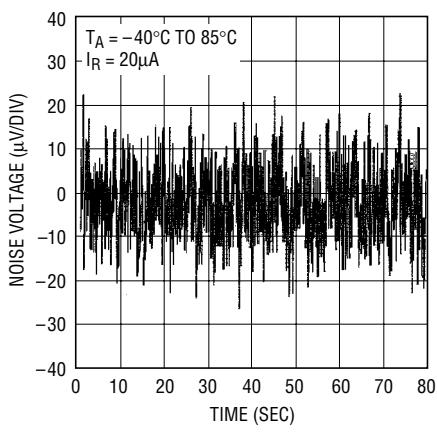
1634-4 G05

Forward Characteristics



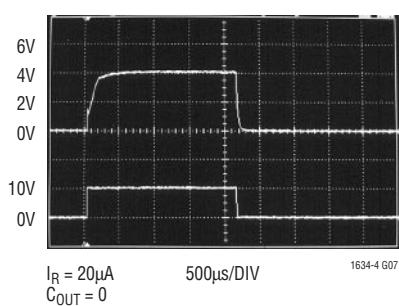
1634-2.5 G06

0.1Hz to 10Hz Noise

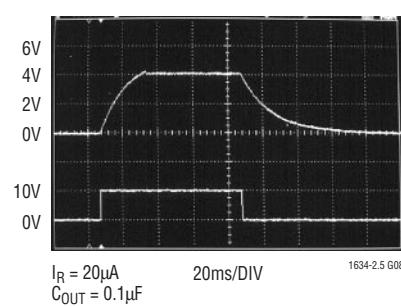


1634-4 G06

Response Time

 $I_R = 20 \mu\text{A}$ $C_{\text{OUT}} = 0$

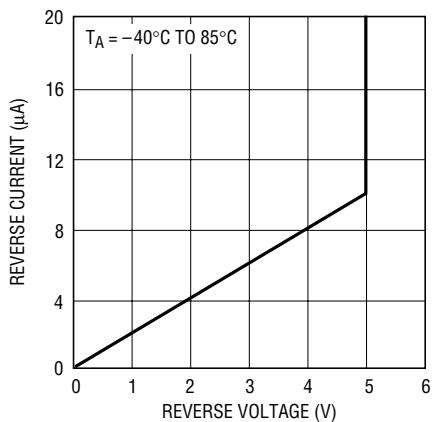
Response Time

 $I_R = 20 \mu\text{A}$ $C_{\text{OUT}} = 0.1 \mu\text{F}$

1634fb

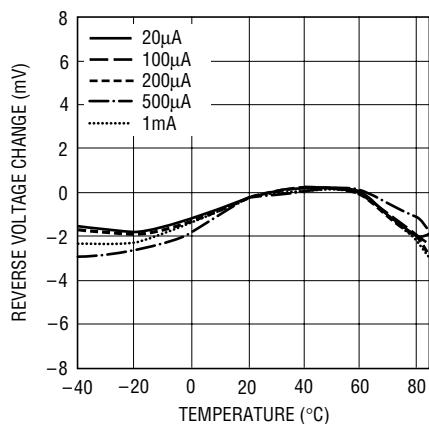
5V TYPICAL PERFORMANCE CHARACTERISTICS

Reverse Characteristics



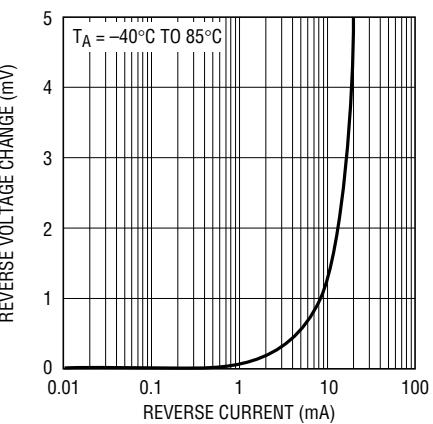
1634-5 G01

Temperature Drift



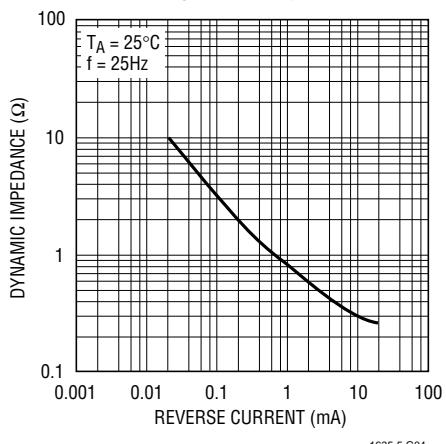
1634-5 G02

Reverse Voltage Change vs Current



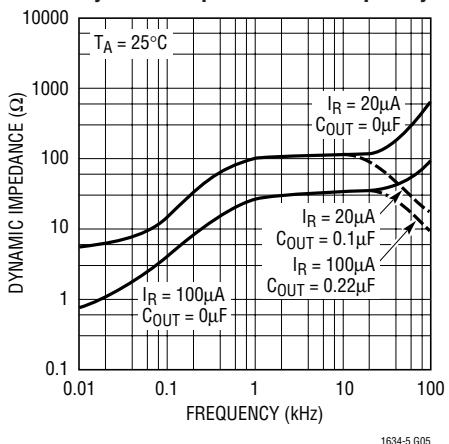
1634-5 G03

Reverse Dynamic Impedance



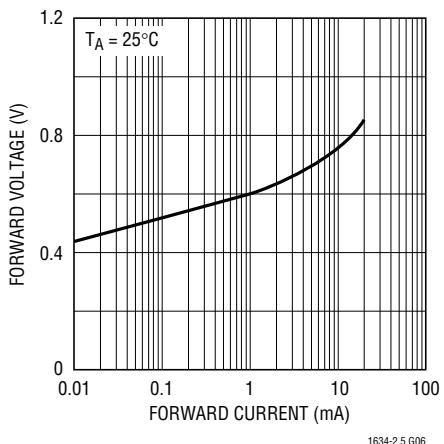
1634-5 G04

Dynamic Impedance vs Frequency



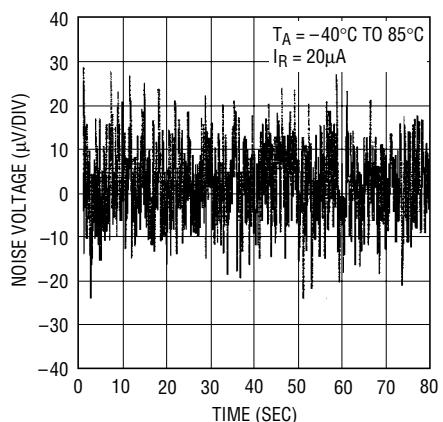
1634-5 G05

Forward Characteristics



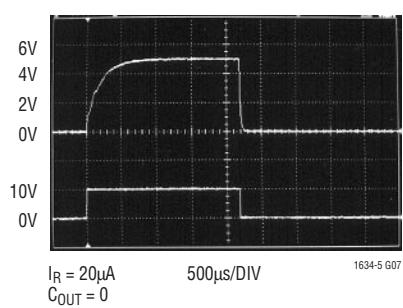
1634-2.5 G06

0.1Hz to 10Hz Noise

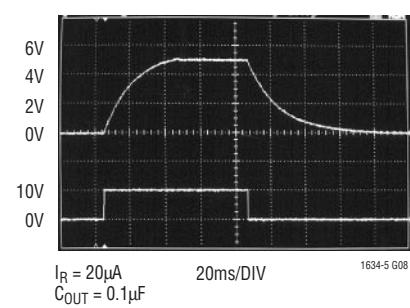


1634-5 G06

Response Time



Response Time



APPLICATIONS INFORMATION

The reverse characteristics of the LT1634 behave like a resistor in parallel with a Zener diode. This simple, well behaved characteristic is important to the proper operation of circuits like Figure 1. The adjustable output voltage

reference depends upon positive feedback from the LT1495's output to start-up and regulate the bias current for the LT1634.

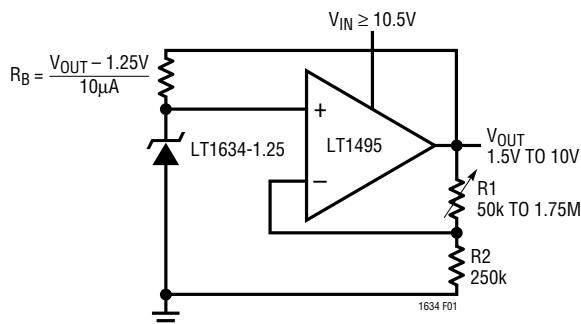
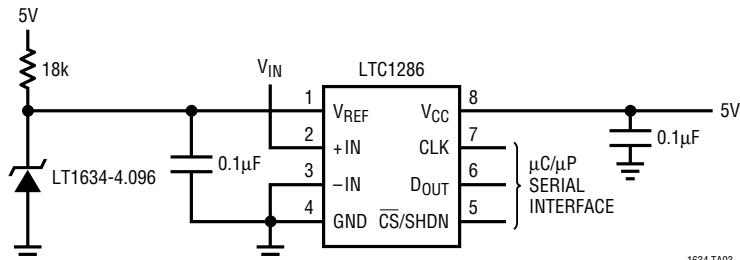
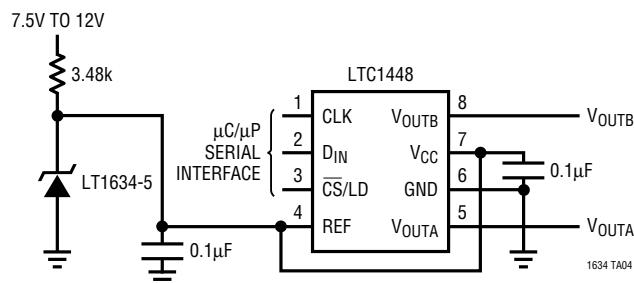


Figure 1. Adjustable Output Voltage Reference

TYPICAL APPLICATIONS**Reference for Micropower A/D Converter**

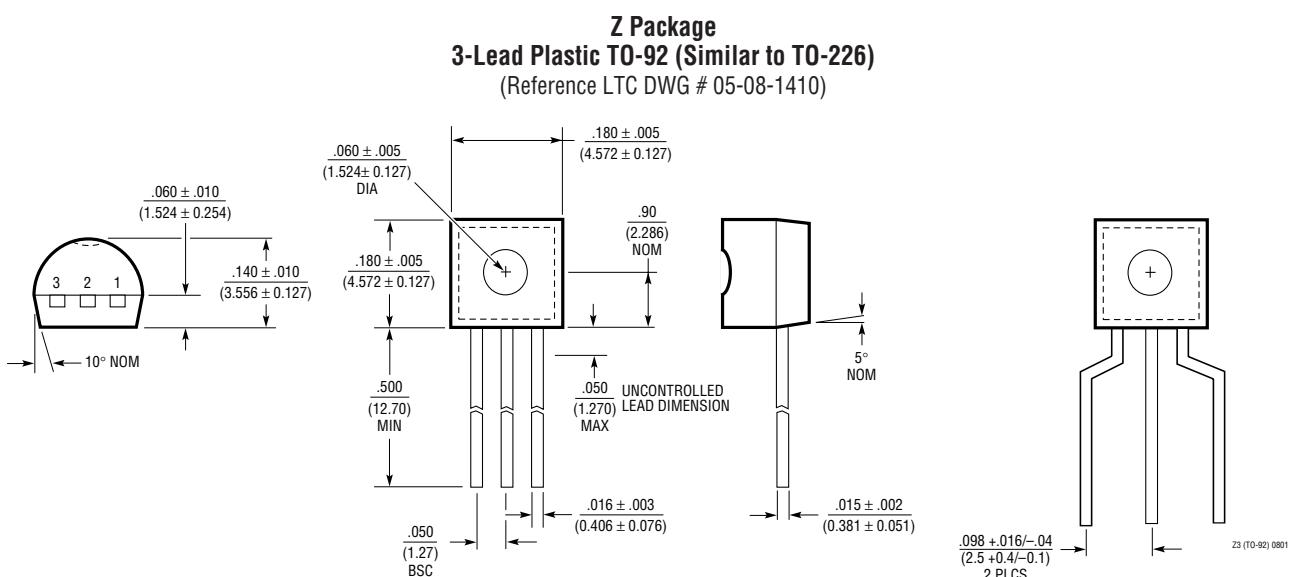
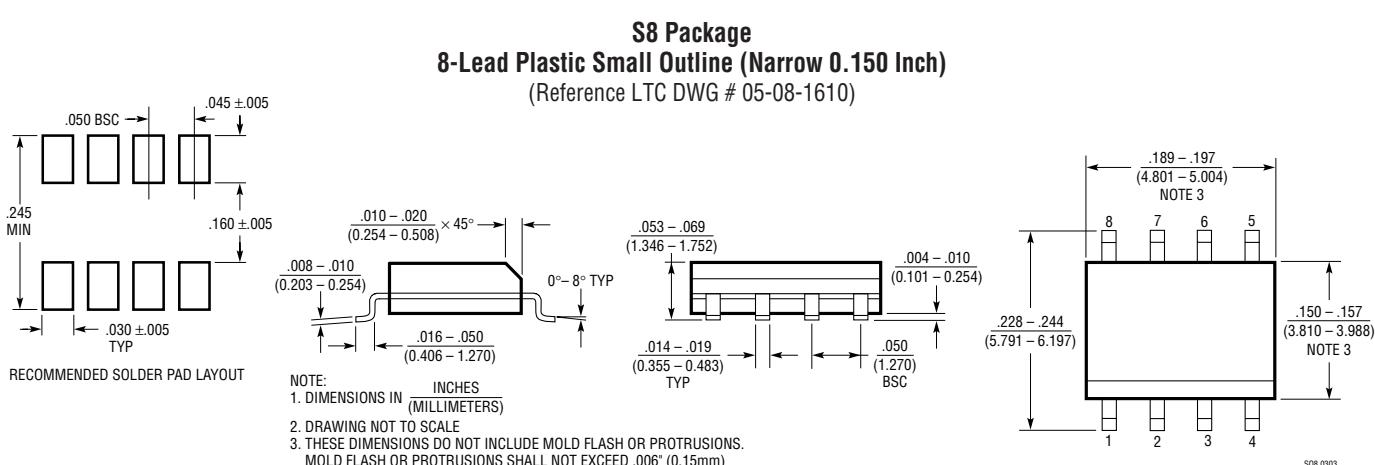
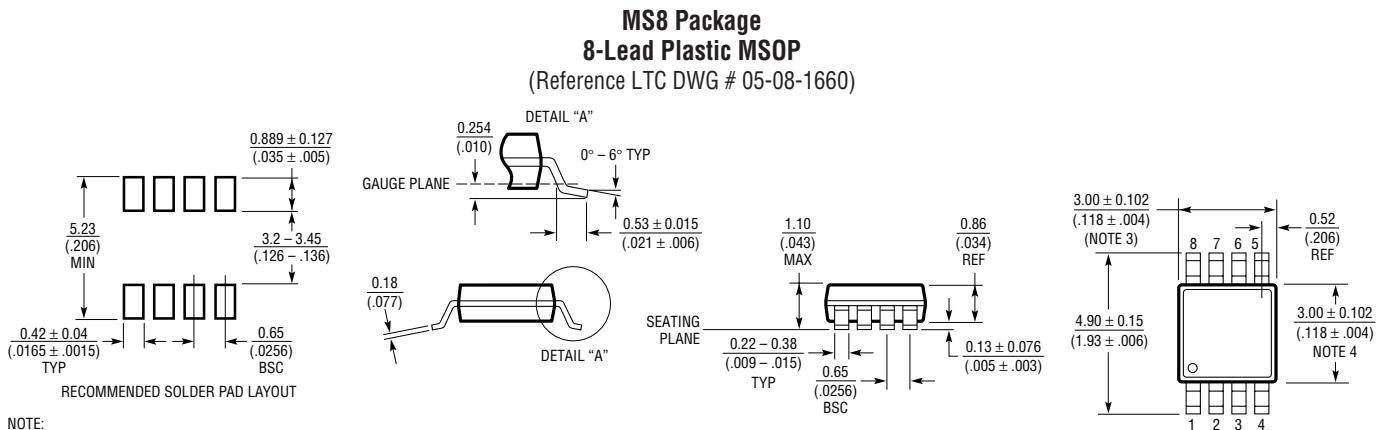
1634 TA03

The LT1634-5 Generates the LTC1448 Dual 12-Bit DAC's Reference and Supply Voltage

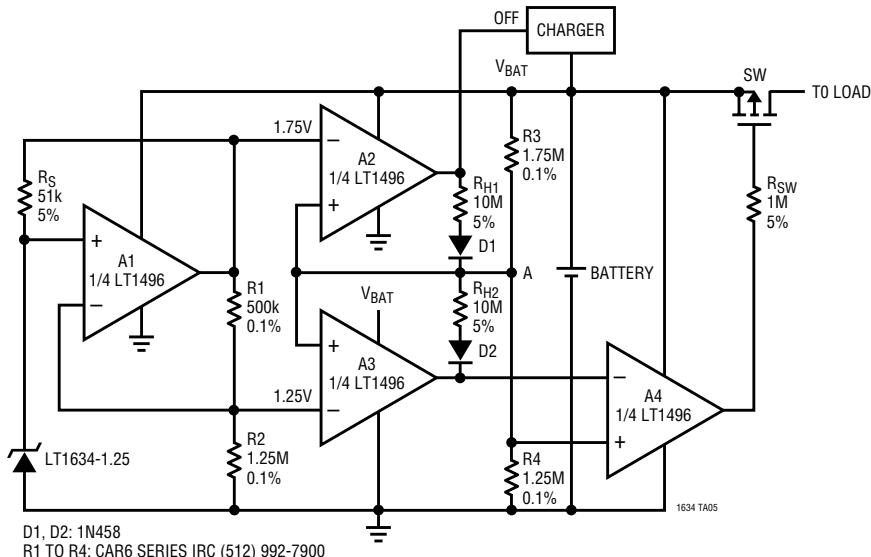
1634 TA04

1634fb

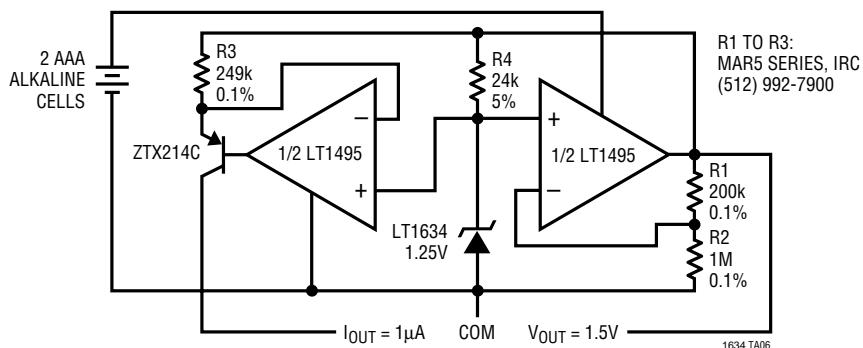
PACKAGE DESCRIPTION



TYPICAL APPLICATIONS

Single Cell Li-Ion Battery Supervisory Circuit ($I_Q = 20\mu A$)

Micropower Voltage and Current Reference



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1440	Micropower Comparator with Reference	3.7 μA Max Supply Current, 1% 1.182V Reference, MSOP, PDIP and SO-8 Packages
LT1460	Micropower Series Reference	0.075% Max, 10ppm/ $^{\circ}C$ Max Drift, 2.5V, 5V and 10V Versions, MSOP, PDIP, SO-8, SOT-23 and TO-92 Packages
LT1495	1.5 μA Precision Rail-to-Rail Dual Op Amp	1.5 μA Max Supply Current, 100pA Max I_{OS}
LTC1540	Nanopower Comparator with Reference	600nA Max Supply Current, 2% 1.182V Reference, MSOP and SO-8 Packages